

Features

Patent Number: 86474, 84545(R.O.C)

- Operating Voltage: 2.0V~5.5V
- · Low standby current
- Low memory retention current: 0.1µA (Typ.)
- Tone/Pulse switchable
- 32 (pulse)/31 (tone) digits for redialing
- Pause and $P \rightarrow T$ key for PBX
- 4×4 keyboard matrix
- 3.58MHz crystal or ceramic resonator
- Hand-free control

- Pause, $P \rightarrow T$ can be saved for redialing WW.0ZSC.CO
- One-key redialing
- Keytone output
- Pause time: 2.2s
- Cascadable manual dialing after redialing
- Calibrated DTMF timing for redialing
- HT93214A: 16-pin DIP package HT93214B/AT: 18-pin DIP package

General Description

The HT93214 are dialer series designed for low cost telephone set applications with expandable features such as Lock function, keytone and LCD display interface. With a 4×4 keyboard, it performs normal tone/pulse switchable dialing, and provides one-key redialing function with a 32-digit memory for speed dial-WWW.DZSG.CON

ing. An on-chip oscillator is built-in to work with an external 3.58Mhz crystal or ceramic resonator for accurate timing. The HT93214 provides 300ms (F1 key) and 600ms (F2 key) of flash time; Tone dialing and 10pps, 20pps selection with 1/2 M/B ratio for pulse dialing.

Selection Table

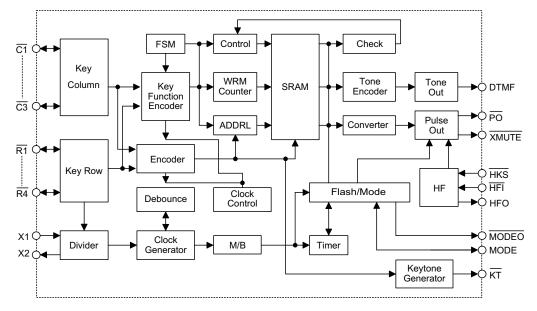
HT93214 series

Function Part No.	Hand- Free	Key Tone	Flash	Flash Time (ms)	Pulse No.	Tone Duration (ms)	Inter Tone Pause (ms)	PPS	M/B	PKG DIP 300mil
HT93214A			Control	300/600	N	94	96	10/20	1/2	16
HT93214B	\checkmark		Control	300/600	N	94	96	10/20	1/2	18
HT93214AT		\checkmark	Control	300/600	N	94	96	10/20	1/2	18





Block Diagram



Pin Assignment

_		_	HEO 🗖 1			
нкѕ⊏	1 16	$\Box \overline{R4}$				
MODE	2 15	□ R3	MODE 🗆 3	16 🗆 R 3	X1 🗖 3	16 🗖 R2
X1□	3 14	$\Box \overline{R2}$	X1 🗖 4	15 🗖 R2	X2 🗖 4	15 🗖 R1
X2□	4 13	$\square \overline{R1}$	X2 🗆 5	14 🗆 R1	VSS 🗖 5	14 🗖 C 3
vss⊏	5 12	□ C3	VSS 🗆 6	13 🗖 🗔		13 🗖 🔁
	6 11	$\Box \overline{C2}$			DTMF 🗖 7	12 🗖 C1
	7 10		DTMF 🗖 8			11 🖵 PO
	8 9	□ P O	XMUTE 🗆 9	10 🗆 PO		10 🗆 кт
l	HT93214A	N	нт	93214B	нт	93214AT
	- 16 DIP-/	4	-1	8 DIP-A		18 DIP-A

Keyboard Information

				HKS
R1 -(1	2	3	F1
R2 -(4	5	6	(F2)
R3 -(7	8	9	(P)
R4 -(*/T	0	#	R

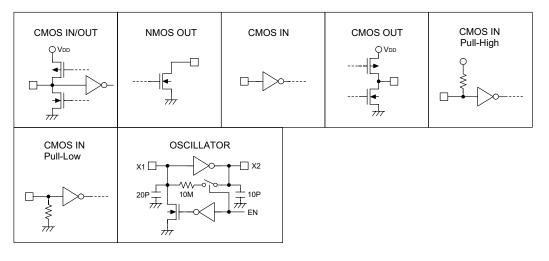


Pin Description

Pin Name	I/O	Internal Connection	Description
C1~C3 R1~R4	I/O	CMOS I/O	These pins along with the $\overline{\text{HKS}}$ form a 4×4 keyboard matrix which can perform keyboard input detection. When on-hook ($\overline{\text{HKS}}$ =high) all the pins are set high. While off-hook the column group ($\overline{\text{C1}}$ - $\overline{\text{C3}}$) is set low and the row group ($\overline{\text{R1}}$ - $\overline{\text{R4}}$) remains high for input detection. Pressing a key connects a single row to a single column $\overline{\text{HKS}}$ and actuates the system oscillator that results in a dialing signal output. If more than two keys are pressed at the same time, no response occurs. The key-in debounce time is 20ms.
X1	Ι		The system oscillator consists of an inverter, a bias resistor and the necessary load
X2	0	OSC	capacitor on chip. Connecting a standard 3.579545MHz crystal or ceramic resona- tor to the X1 and X2 terminals can implement the oscillator function. The oscillator is turned off in the standby mode, and is actuated whenever a keyboard entry is de- tected.
XMUTE	0	NMOS Open Drain	NMOS open drain structure pulled to VSS during dialing signal transmission. Otherwise, it is an open circuit. This pin is used to mute the speech circuit when transmitting the dial signal.
HKS	I	CMOS	This pin is used to monitor the status of the hook-switch and its combination with $\overline{\text{HFI}}$ can control the $\overline{\text{PO}}$ pin output to make or break the line. HKS=VDD: On-hook state ($\overline{\text{PO}}$ =low). Except for $\overline{\text{HFI}}$ (hand-free control input), other functions are all disabled. HKS=VSS: Off-hook state ($\overline{\text{PO}}$ =high). The chip is in the stand-by mode and ready to receive the key input.
PO	0	NMOS	NMOS open drain output structure, which by receiving the HKS and HFO signals control the dialer so as to connect or disconnect the telephone line. PO is pulled to VSS when HKS is high (on-hook) and HFO is low. PO is an open circuit which make the line connection when HKS is low (off-hook) or HFO is high. During the off-hook state, this pin also outputs the dialing pulse train in pulse mode dialing. While in the tone mode, this pin is always an open circuit.
MODE	I/O	CMOS	This is a tri-state input/output pin, used for dialing mode selection, either Tone mode or Pulse mode, 10pps/20pps MODE=VDD: Pulse, 10pps, M/B=1/2 MODE=Floating: Pulse, 20pps, M/B=1/2 MODE=VSS: Tone. The MODE selection is checked each time a key input is received.
DTMF	0	CMOS	This pin is active only when the chip transmits tone dialing signals. Otherwise, it always outputs a low. The pin outputs tone signals to drive the external transmitter amplifier circuit. The load resistor (to V_{SS}) should not be less than $5k\Omega$ and any DC load connected to V_{DD} is not allowed.
ΚT	0	NMOS	NMOS open drain structure for keytone output. It outputs 34ms of 600Hz tone burs when any key is pressed in the pulse mode or when a function key is pressed in the tone mode.
HFI	I	CMOS	Pulled-high, this pin is a Schmitt trigger input structure. Active low. Applying a negative going pulse to $\overline{\text{HFI}}$ can toggle the HFO once and hence control the hand-free function. The pull-high resistance of $\overline{\text{HFI}}$ is about 200k Ω typ. An external RC net work is recommended for input debouncing.
HFO	0	CMOS	The HFO pin is a CMOS output structure. Its output is toggle- controlled by a negative transition on $\overline{\text{HFI}}$ pin. When HFO is high, the hand-free function is enabled and PO outputs a high to connect the line. The hand-free function can be released by an on-off-hook operation or by anothe HFI input. Refer to the functional description for the hand-free functional operation.
VDD	_		Positive power supply, 2.0V~5.5V for normal operation
VSS	_		Negative power supply, ground
MODEO	0	NMOS	NMOS open drain output pin pulled to VSS during tone output and is an open circui during pulse output.



Approximate internal connection circuits



Absolute Maximum Ratings

Supply Voltage0.3V to 6V	Storage Temperature50°C to 125°C
Input VoltageV_SS^-0.3V to V_DD^+0.3V	Operating Temperature20°C to 75°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Electrical Characteristics

F_{OSC}=3.5795MHz, Ta=25°C

Symbol	Parameter		Test C	onditions	Min.	Tran	Max.	Unit
Symbol	Parameter	V_{DD}	Conditions		win.	Тур.	wax.	Omt
V _{DD}	Operating Voltage	_		_	2	_	5.5	V
IDD	Operating Current	2.5V	Pulse	Off-hook	_	0.2	1	mA
לטי	Operating Current	2.50	Tone	Keypad entry		0.6	2	mA
I _{STB}	Standby Current	1V	On-hoo No entr	k, no load y	_		1	μA
V _R	Memory Retention Voltage	—		_	1	_	5	V
I _R	Memory Retention Current	1V	On-hook			0.1	0.2	μA
VIL	Input Low Voltage		_		V _{SS}	_	$0.2V_{DD}$	V
VIH	Input High Voltage	_		—		_	V _{DD}	V
I _{XMO}	XMUTE Leakage Voltage	_	V _{XMUTE}		_	_	1	μA
I _{OLXM}	XMUTE Sink Current	2.5V	VXMUTE	=0.5V	1	_	_	mA
IHKS	HKS Pin Input Current	2.5V	V _{HKS} =2	.5V			0.1	μA
R _{HFI}	HFI Pull- High Resistance	2.5V	V _{HFI} =0∖	/		200		kΩ
I _{OH1}	Keypad Pin Source Current	2.5V	V _{OH} =0V	V _{OH} =0V		_	-40	μA
I _{OL1}	Keypad Pin Sink Current	2.5V	V _{OL} =2.5V		200	400		μA
I _{OH2}	HFO Pin Source Current	2.5V	V _{OH} =2V		-1	_		mA
I _{OL2}	HFO Pin Sink Current	2.5V	V _{OL} =0.5V		1		_	mA
I _{OL3}	MODEO Sink Current	2.5V	V _{OL} =0.5	δV	0.6	3.5	_	mA



HT93214 Series

Symbol	Parameter		Test Conditions	Min.	Тур.	Max.	Unit
Symbol	Falalletei	$\boldsymbol{V}_{\text{DD}}$	Conditions	IVIII.	тур.	Wax.	Unit
T _{FP}	Pause Time After Flash	2.5V	—	—	800	—	ms
T _{RP}	One-key Redialing Pause Time	2.5V	_		800		ms
Fosc	System Frequency		_	_	3.58		MHz
T _{DB}	Key-in Debounce Time	2.5V	_		20		ms
T _{BRK}	Break Time For One-key Redialing	2.5V	_	_	2.2	_	s
т	T Official Data Time		10pps		800		
	Off-hook Delay Time	2.5V	20pps	_	500	_	ms

Pulse Mode Electrical Characteristics

F_{OSC}=3.5795MHz, Ta=25°C

Symbol	Devementer		Test Conditions	Min	Turn	Max	11::4	
Symbol	Parameter	V_{DD}	Conditions	Min.	Тур.	Max.	Unit	
I _{POH}	PO Output Source Current	2.5V	V _{OH} =2V	-0.2			mA	
I _{POL}	PO Output Sink Current	2.5V	V _{OL} =0.5V	0.2	0.6		mA	
P _R	Pulse Rate		MODE pin is connected to V _{DD}		10		pps	
			MODE pin is opened		20			
M/B	Make/Break Ratio		_		33:66		%	
-			M/B=33:66 (10 pps)		33			
T _{PDP}	Pre-digit-pause Time	_	M/B=33:66 (20 pps)		17		ms	
-	Internal of a second Theorem		10 pps		800			
T _{IDP}	Inter-digit-pause Time	_	20 pps		500		ms	
-	Duba Maha Durakan		10 pps, M/B=1/2		33.3			
Тм	Pulse Make Duration		20 pps, M/B=1/2		16.7		ms	
-			10 pps, M/B=1/2	_	66.6			
Тв	Pulse Break Duration		20 pps, M/B=1/2		33.3		ms	
T _P	Pause Time		_		2.2		s	

Tone Mode Electrical Characteristics

F_{OSC}=3.5795MHz, Ta=25°C

Symbol	Parameter		Test Conditions	Min.	Tun	Max.	Unit
Symbol	Falalleter	V_{DD}	Conditions	IVIII.	Тур.	Wax.	Unit
V _{TDC}	DTMF Output DC Level		No load	$0.45V_{DD}$		$0.7V_{DD}$	V
I _{TOL}	DTMF Sink Current	2.5V	V _{DTMF} =0.5V	0.1			mA
V _{TAC}	DTMF Output AC Level	_	Row group, R _L =5kΩ	0.12	0.155	0.18	Vrms
RL	DTMF Output Load	2.5V	THD≤–23dB	5		_	kΩ
A _{CR}	Column Pre-emphasis	2.5V	Row group=0dB	1	2	3	dB
THD	Tone Signal Distortion	2.5V	$R_L=5k\Omega$	_	-30	-23	dB
T _{TMIN}	Minimum Tone Duration		Auto-redial	_	94		ms
T _{ITPM}	Minimum Inter-Tone Pause		Auto-redial		96	_	ms

THD (Distortion) (dB) = 20 log $(\sqrt{V1^2 + V2^2 + ... + Vn^2} / \sqrt{Vi^2 + Vh^2})$

Vi, Vh: Row group and column group signals

V1, V2, ... Vn: Harmonic signals (BW=300Hz~3500Hz)



Functional Description

Keyboard matrix

 $\overline{C1}$ ~ $\overline{C3}$, \overline{HKS} and $\overline{R1}$ ~ $\overline{R4}$ form a keyboard matrix. Together with a standard 4×4 keyboard, the keyboard matrix is used for dialing entries. The keyboard arrangement of the HT93214 series is shown in the **Keyboard Information**.

Tone frequency

Tone	Output Free	Output Frequency (Hz)				
Name	Specified	Actual	% Error			
R1	697	699	+0.29%			
R2	770	766	-0.52%			
R3	852	847	-0.59%			
R4	941	948	+0.74%			
C1	1209	1215	+0.50%			
C2	1336	1332	-0.30%			
C3	1477	1472	-0.34%			

Note: % Error does not contain the crystal frequency drift

Dialing specification selection

• The specifications are selected by the MODE pin.

MODE	Tone/Pulse	Dial Rate	M/B Ratio
VDD	Pulse	10pps	1/2
VSS	Tone	_	_
Floating	Pulse	20pps	1/2

• The MODE pin status is checked whenever a digit key is pressed, however the M/B and pulse rate are determined at the first key entry.

Hand-free function operation

- When HFO is low, a falling edge triggers the HFI, enabling the Hand-free function (HFO becomes high).
- Reset Hand-free function When HFO is high, the Hand-free function is enabled and can be reset by:
 - Off-hook
 - Applying a falling edge to HFI
- Hand-free function table

Current	State	Next State				
Hook SW	HFO	Input	HFO	Dialing?		
	Low	HFI↓	High	Yes		
On-hook	High	HFI↓	Low	No		
Off-hook	High	HFI↓	Low	Yes		
On-hook		of off-hook	Low	Yes		
Off-hook	Low	on-hook	Low	No		
Off-hook	High	on-hook	High	Yes		

Flash

Two flash keys are provided, namely F1, F2 for both series. All the flash key function as control key with different break duration. Whenever a flash key is pressed the \overline{PO} pin will be forced low for a T_F duration and the transmission of the new digit key inputs will be further delayed for a T_{FP} after T_F. See the following table for flash duration selection.

Item	F1	F2
HT93214	300ms	600ms

Key definition

• 0,1,2,3,4,5,6,7,8,9 keys These are dialing number input keys for both the pulse mode and the tone mode operation.

• */T

This key executes the P \rightarrow T function and waits a T_{P \rightarrow T} duration in the pulse mode. On the other hand, the */T key executes the * function in the tone mode. The */T key will occupy one memory digit in either tone or pulse mode.

•

This is a dialing signal key for the tone mode only, no response in the pulse mode.

• F1, F2

Pressing one of the flash keys will force the \overrightarrow{PO} pin to become low for the T_F duration. To transmit the dial signals of the key input that are entered after the F key, a wait period T_{FP} (sec) after \overrightarrow{PO} pin returns from low is provided.

• P

Pause key. The execution of this key pauses the output for the T_P duration (2.2s).

• R

Redial key. It executes redialing as well as one-key redial function.



Keyboard Operation

The following operations are described under an on-off- hook or on-hook condition with the hand-free active condition.

- Normal dialing
 - Pulse mode Tone mode (a) without */T (a) without */T Keyboard input: D1 D2 ... Dn Keyboard input: D1 D2 ... Dn Dialing output: D1 D2 ... Dn Dialing output: D1 D2 ... Dn RM: D1 D2 ... Dn RM: D1 D2 ... Dn (b) with */T (b) with */T Keyboard input: D1 D2 ... Dn */T Dn+1 ... Keyboard input: D1 D2 ... Dn */T Dn+1 ... Dm Dm Dialing output: D1 D2 ... Dŋ TP→T Dn+1 ... Dm Dialing output: D1 D2 ... Dn * Dn+1 ... Dm Pulse Tone RM: D1 D2 ... Dn * Dn+1 ... Dm RM: D1 D2 ... Dn */T Dn+1 ... Dm
 - Note: The maximum capacity of the RM memory is 32 digits. When more than 32 digits are entered, the signal is transmitted but the redial function is inhibited.

```
    Redial
```

```
    Pulse mode
```

(a) without */T RM content: D1 D2 ... Dn Keyboard input: R Dialing output: D1 D2 ... Dn RM: Unchanged

```
    Tone mode

            (a) without */T
            RM content: D1 D2 ... Dn
            Keyboard input: R
            Dialing output: D1 D2 ... Dn
```

```
(b) with */T
RM content: D1 D2 ... Dn */T Dn+1 ... Dm
Keyboard input: R
Dialing output: D<u>1 D2 ... Dn</u> TP→T D<u>n+1 ... D</u>m
Pulse Tone
RM: Unchanged
```

```
(b) with */T
RM content: D1 D2 ... Dn */T Dn+1 ... Dm
```

RM: Unchanged

Keyboard input: R Dialing output: D1 D2 ... Dn * Dn+1 ... Dm RM: Unchanged



One-key redial

 Pulse mode

 (a) without */T
 Keyboard input: D1 D2 ... Dn R
 Dialing output: D1 D2 ... Dn TBRK TRP D1 D2 ... Dn
 RM: D1 D2 ... Dn

```
(b) with */T

Keyboard input: D1 D2... Dn */T Dn+1 ...

Dm R

Dialing output: D1 D2 ... Dn TP\rightarrowT Dn+1...Dm

Pulse

TBRK TRP D1 D2 ... Dn TP\rightarrowT

Pulse

Dn+1...Dm

Tone

RM: D1 D2 ... Dn */T Dn+1 ... Dm
```

(a) without */T
Keyboard input: D1 D2 ... Dn R
Dialing output: D1 D2 ... Dn TBRK TRP D1 D2 ... Dn
RM: D1 D2 ... Dn
(b) with */T
Keyboard input: D1 D2 ... Dn */T Dn+1 ... Dm R
Dialing output: D1 D2 ... Dn * Dn+1 ... Dm
TBRK TRP D1 D2 ... Dn * Dn+1 ... Dm

```
RM: D1 D2 ... Dn * Dn+1 ... Dm
```

Note: If the dialing number exceeds 32 digits, redialing is inhibited and $\overline{\text{PO}}$ =open

Flash

Flash as a control key
 Keyboard input: D1 D2 ... Dn F Dn+1 ...
 Dm
 Dialing output: D1 D2 ... Dn TF TFP Dn+1 ...
 Dm
 RM: Dn+1 ... Dm

Note: TF: break a flash time

Pause

- Tone mode

Keyboard input: $D1D2 \dots Dn P Dn+1 \dots Dm$ Dialing output: D1 D2 ... Dn T_P Dn+1 ... Dm RM: D1 D2 ... Dn P Dn+1 ... Dm

Note

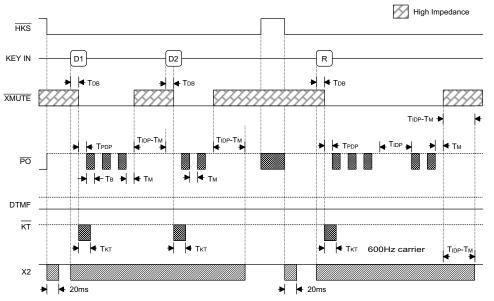
RM: Redial memory D1 D2 ... Dn: 0~9 Dn+1 ... Dm: 0~9, * , #

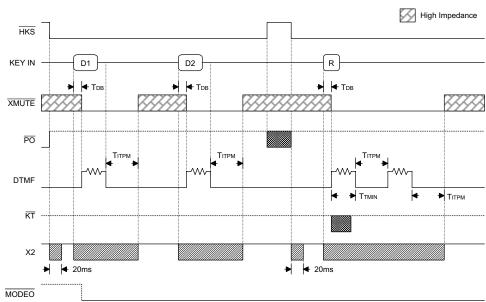


Timing Diagrams

Normal dialing

Pulse mode





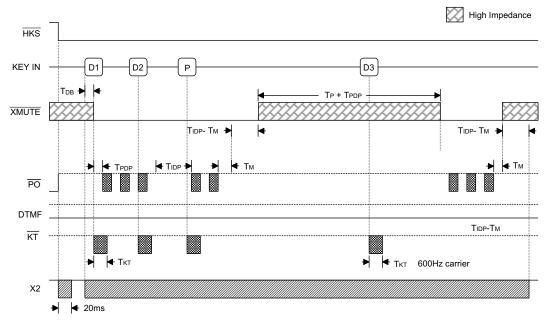
Tone mode

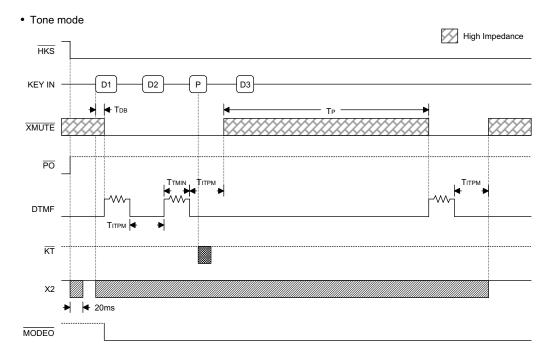


HT93214 Series

Dialing with PAUSE key



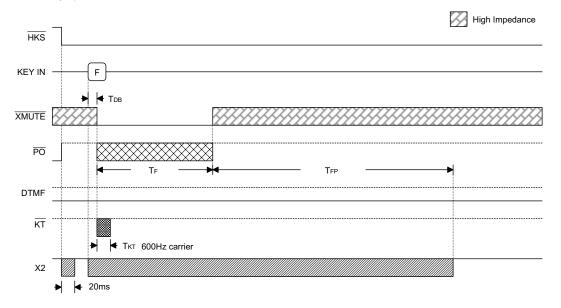




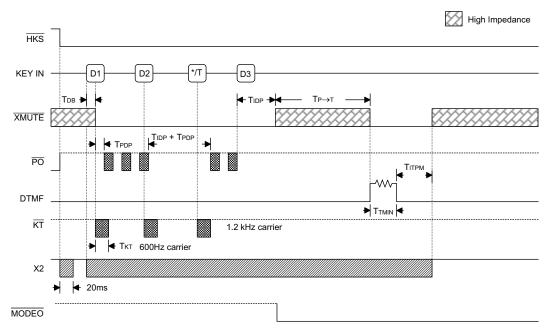


HT93214 Series

Flash key operation

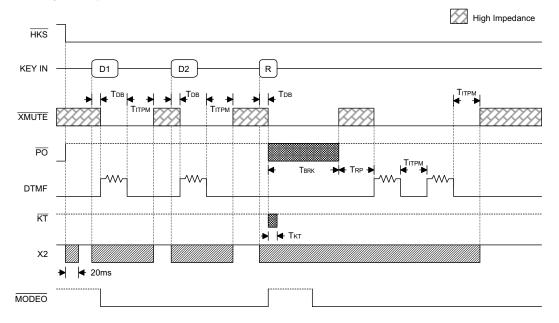


• Pulse to Tone operation



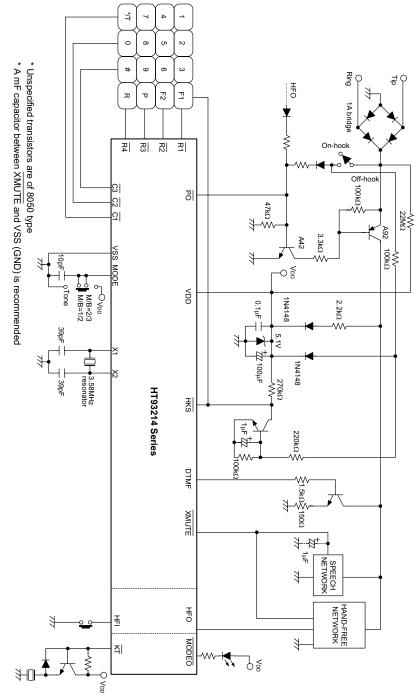


One key redial operation





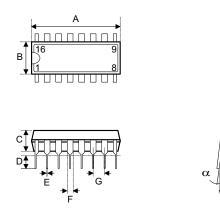
Application Circuits





Package Information

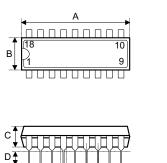
16-pin DIP (300mil) outline dimensions



Symbol	Dimensions in mil			
	Min.	Nom.	Max.	
A	745	—	775	
В	240		260	
С	125	_	135	
D	125	_	145	
E	16	_	20	
F	50	_	70	
G		100	—	
Н	295		315	
I	335		375	
α	0°	_	15°	



18-pin DIP (300mil) outline dimensions



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Symbol	Dimensions in mil			
	Min.	Nom.	Max.	
A	895	—	915	
В	240	_	260	
С	125	—	135	
D	125	—	145	
E	16	—	20	
F	50	_	70	
G	_	100	_	
Н	295	_	315	
I	335		375	
α	0°		15°	



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